L Number	Hits	Search Text	DB	Time stamp
2	4751	(substrate with thickness) and temperature	USPAT;	2004/02/26 13:30
		and (gap) and (liquid adj crystal)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	4 4
3	19	(substrate with thickness) and (room adj	USPAT;	2004/02/26 13:31
		temperature) and (gap near (icrease or	US-PGPUB;	
		decrease)) and (liquid adj crystal)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	0001/00/05 10 15
4	58	((cell adj gap) and (thermal adj expans\$4))	USPAT;	2004/02/26 13:46
		and (room adj temperature)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_		(/	IBM_TDB	2004/02/26 13:47
6	60	((cell adj gap) near10 (increase or	USPAT; US-PGPUB;	2004/02/26 13:47
	!	decrease)) and (room adj temperature)	EPO; JPO;	
			DERWENT;	
	1		IBM TDB	
_	4.2	((cell adj gap) and (thermal adj expans\$4))	USPAT;	2004/02/26 13:53
7	43	((Cell ad) gap) and (thermal ad) expanss*//	US-PGPUB;	2004/02/20 13:33
		same temperature	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	382	349/155	USPAT	2002/06/26 20:45
	1169	1	USPAT; JPO	2002/06/24 20:01
_	1118	349/153	USPAT; JPO	2002/06/24 16:32
_	176	349/190	USPAT; JPO	2002/06/24 16:33
_	21	((cell adj gap) and (thermal adj expans\$4))	USPAT; JPO	2003/05/12 14:18
		same temperature	,	
-	8	(((cell adj gap) and (thermal adj expans\$4))	USPAT; JPO	2002/06/24 20:03
i		same temperature) and 349/155		
l - j	193	349/155 and (cell adj gap)	USPAT; JPO	2002/06/26 14:23
-	47	349/190 and (cell adj gap)	USPAT; JPO	2002/06/24 21:03
-	115	349/153 and (cell adj gap)	USPAT; JPO	2002/06/24 21:04
-	1991	(liquid adj crystal) and (cell adj gap)	USPAT; JPO	2002/06/26 14:25
-	57	(liquid adj crystal) and ((cell adj gap)	USPAT; JPO	2002/06/26 14:26
		same center)	IIODA III	2002/06/26 20:46
-	179		USPAT	2002/06/26 20:46
-	179		USPAT	2003/01/13 17:16 2003/01/13 16:56
- '	121	((cell adj gap) and (thermal adj expans\$4))	USPAT; US-PGPUB;	2003/01/13 16:56
		and temperature	JPO	
- 1	1.56	349/158 and (substrate with thickness) and	USPAT;	2003/01/13 17:17
-	166		US-PGPUB;	2003/01/13 17:17
		temperature	JPO	
	36	349/158 and (substrate with thickness)and	USPAT;	2003/05/12 14:22
-	ه د	temperature and gradua\$4	US-PGPUB;	
		competatate and graduays	JPO	
_	12451	(substrate with thickness) and temperature	USPAT;	2003/01/13 18:11
	12451	and gradua\$4	US-PGPUB;	
		J-2	JPO	A 1
_	2079	(substrate with thickness) and temperature	USPAT;	2003/01/13 18:13
	20.7	and gradua\$4 and (liquid adj crystal)	US-PGPUB;	
			JPO	
-	1081	(substrate with thickness) and temperature	USPAT;	2003/01/14 10:32
		and gradua\$4 and (liquid adj crystal) and gap	US-PGPUB;	
			JPO	
-	0	(substrate with thickness) and temperature	USPAT;	2003/01/13 18:18
		and gradua\$4 and (liquid adj crystal) and gap	US-PGPUB;	
		and ((irregular with color) with	JPO	
		temperature)		
-	10	(substrate with thickness) and temperature	USPAT;	2003/01/14 10:21
		and gradua\$4 and (liquid adj crystal)and gap	US-PGPUB;	
		and (irregular with temperature)	JPO	
-	29	(substrate with thickness) and temperature	USPAT;	2003/01/14 10:31
		and gradua\$4 and (liquid adj crystal) and gap	US-PGPUB;	
l	1	and 349/158	JPO	

-	127	(substrate with thickness) and temperature	USPAT;	2003/05/12 14:23
		and (gap same gradua\$4) and (liquid adj	US-PGPUB;	
		crystal)	JPO	
-	342	349/158 and (substrate with thickness)	USPAT;	2003/01/14 10:42
			US-PGPUB;	
			JPO	
-	37	((cell adj gap) and (thermal adj expans\$4)) same temperature	USPAT;	2004/02/26 13:27
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	140		USPAT;	2004/02/26 13:29
		and (gap same gradua\$4) and (liquid adj	US-PGPUB;	
		crystal)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	38	·	USPAT;	2003/05/12 14:28
		temperature and gradua\$4	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	